

2SC124 Transistors

Si NPN LP HF BJT

Military/High-Rel N

V(BR)CEO (V) 25

V(BR)CBO (V) 40

I(C) Max. (A) 25m

Absolute Max. Power Diss. (W) 250m

Maximum Operating Temp (°C) 175

I(CBO) Max. (A) .20u

@V(CBO) (V) (Test Condition)

h(FE) Min. Current gain. 40

h(FE) Max. Current gain.

@I(C) (A) (Test Condition) .05m

@V(CE) (V) (Test Condition) 10

f(T) Min. (Hz) Transition Freq 200M

@I(C) (A) (Test Condition)

@V(CE) (V) (Test Condition)

V(CE)sat Max. (V)

@I(C) (A) (Test Condition)

@I(B) (A) (Test Condition)

h(fe) Min. SS Current gain.

@I(C) (A) (Test Condition)

@V(CE) (V) (Test Condition)